High Current Bias Resistor Transistor

PNP Silicon

Features

• Collector -Emitter Sustaining Voltage -

$$V_{CEO(sus)} = 30 \text{ Vdc (Min)} @ I_C = 10 \text{ mAdc}$$

• High DC Current Gain -

$$h_{FE}$$
 = 125 (Min) @ I_C = 0.8 Adc
= 90 (Min) @ I_C = 3.0 Adc

• Low Collector -Emitter Saturation Voltage -

$$V_{CE(sat)} = 0.275 \text{ Vdc (Max)} @ I_C = 1.2 \text{ Adc}$$

= 0.55 Vdc (Max) @ I_C = 3.0 Adc

• SOT-223 Surface Mount Packaging

• ESD Rating - Human Body Model: Class 1B

- Machine Model: Class B

 These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_C = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	30	Vdc
Collector-Base Voltage	V _{CB}	45	Vdc
Emitter-Base Voltage	V _{EB}	±6.0	Vdc
Base Current – Continuous	Ι _Β	1.0	Adc
Collector Current - Continuous - Peak	Ic	3.0 5.0	Adc
Total Power Dissipation @ T_C = 25°C Derate above 25°C Total P_D @ T_A = 25°C mounted on 1" sq. (645 sq. mm) Collector pad on FR-4 bd material Total P_D @ T_A = 25°C mounted on 0.012" sq. (7.6 sq. mm) Collector pad on FR-4 bd material	P _D	3.0 24 1.56	W mW/°C W
Operating and Storage Junction Temperature Range	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

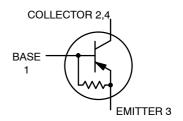
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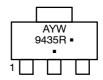
POWER BJT $I_C = 3.0$ AMPERES $BV_{CEO} = 30$ VOLTS $V_{CE(sat)} = 0.275$ VOLTS





SOT-223 CASE 318E STYLE 1

MARKING DIAGRAM



A = Assembly Location

Y = Year
W = Work Week
9435R = Device Code
• Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NSB9435T1G	SOT-223 (Pb-Free)	1000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

THERMAL CHARACTERISTICS

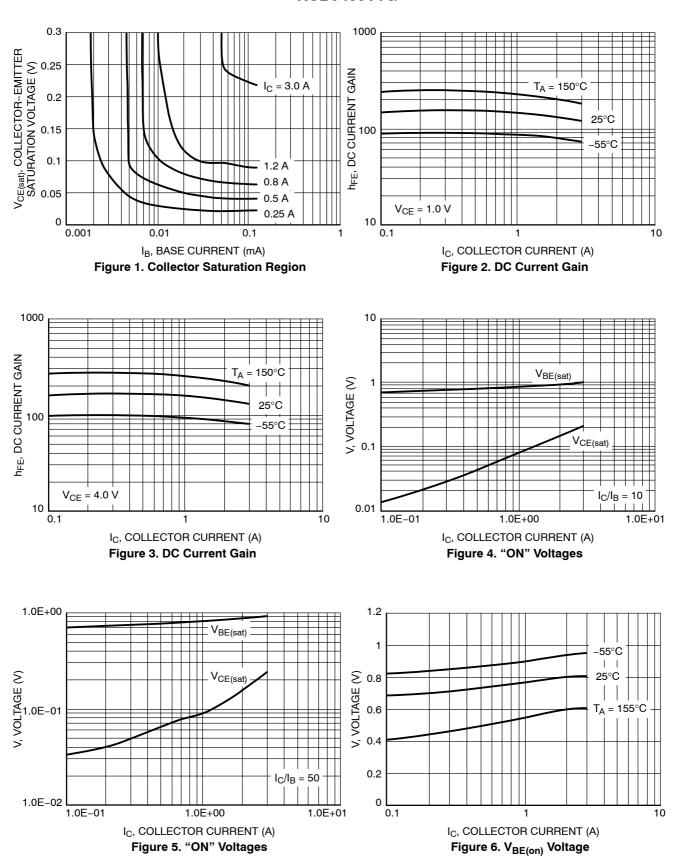
Characteristic	Symbol	Value	Unit
Thermal Resistance Junction-to-Case Junction-to-Ambient on 1" sq.(645 sq. mm) Collector pad on FR-4 board material Junction-to-Ambient on 0.012" sq. (7.6 sq. mm) Collector pad on FR-4 board material	R _θ JC R _θ JA R _θ JA	42 80 174	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 s	T_L	260	°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	<u> </u>	•	•	•	
Collector-Emitter Sustaining Voltage (I _C = 10 mAdc, I _B = 0 Adc)	V _{CEO(sus)}	30	_	-	Vdc
Emitter–Base Voltage ($I_E = 50 \mu Adc$, $I_C = 0 Adc$)	V_{EBO}	6.0	-	-	Vdc
Collector Cutoff Current (V _{CE} = 25 Vdc) (V _{CE} = 25 Vdc, T _J = 125°C)	I _{CER}	_ _	_ _	20 200	μAdc
Emitter Cutoff Current (V _{BE} = 5.0 Vdc)	I _{EBO}	_	_	700	μAdc
ON CHARACTERISTICS (Note 1)					
Collector–Emitter Saturation Voltage ($I_C = 0.8$ Adc, $I_B = 20$ mAdc) ($I_C = 1.2$ Adc, $I_B = 20$ mAdc) ($I_C = 3.0$ Adc, $I_B = 0.3$ Adc)	V _{CE(sat)}	- - -	0.155 - -	0.210 0.275 0.550	Vdc
Base-Emitter Saturation Voltage ($I_C = 3.0$ Adc, $I_B = 0.3$ Adc)	V _{BE(sat)}	_	_	1.25	Vdc
Base-Emitter On Voltage (I _C = 1.2 Adc, V _{CE} = 4.0 Vdc)	V _{BE(on)}	-	_	1.10	Vdc
DC Current Gain $(I_C = 0.8 \text{ Adc}, V_{CE} = 1.0 \text{ Vdc})$ $(I_C = 1.2 \text{ Adc}, V_{CE} = 1.0 \text{ Vdc})$ $(I_C = 3.0 \text{ Adc}, V_{CE} = 1.0 \text{ Vdc})$	h _{FE}	125 110 90	220 - -	- - -	-
Resistor	R1	7.5	10	12.5	kΩ
DYNAMIC CHARACTERISTICS	<u> </u>	•	•	•	
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0 Adc, f = 1.0 MHz)	C _{ob}	-	100	150	pF
Input Capacitance (V _{EB} = 8.0 Vdc)	C _{ib}	-	135	_	pF
Current-Gain - Bandwidth Product (Note 2) (I _C = 500 mA, V _{CE} = 10 V, F _{test} = 1.0 MHz)	f _T	-	110	_	MHz

^{1.} Pulse Test: Pulse Width $\leq 300~\mu\text{s},~\text{Duty Cycle} \leq 2\%.$

^{2.} $f_T = |h_{FE}| \cdot f_{test}$



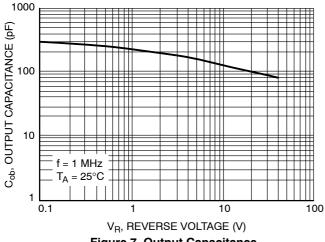
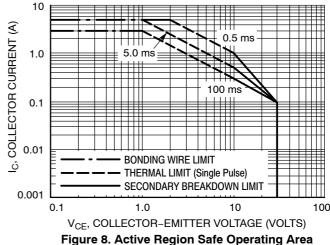


Figure 7. Output Capacitance



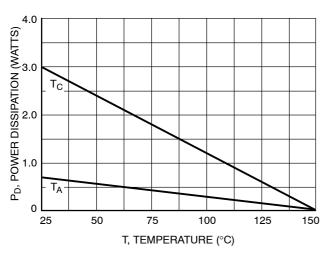


Figure 9. Power Derating

There are two limitations on the power handling ability of a transistor: average junction temperature and secondary breakdown. Safe operating area curves indicate I_C - V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 8 is based on $T_{J(pk)} = 150^{\circ}C$; T_C is variable depending on conditions. Secondary breakdown pulse limits are valid for duty cycles to 10% provided T_{J(pk)} ≤ 150 °C. $T_{J(pk)}$ may be calculated from the data in Figure 10. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by secondary breakdown.

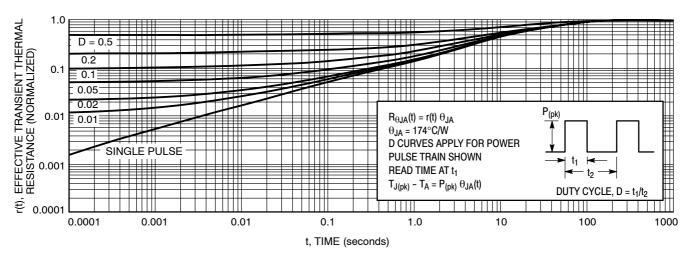
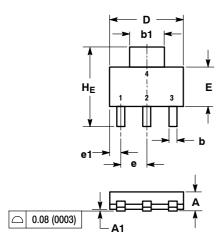


Figure 10. Thermal Response

PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 ISSUE N





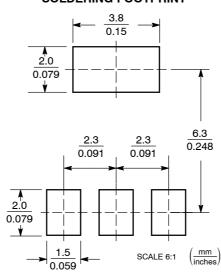
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: INCH.

	MILLIMETERS INCHES					
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
С	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	-	10°

STYLE 1: PIN 1. BASE

- 2. COLLECTOR 3. EMITTER
- 4 COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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